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Vishay Semiconductors

COMPLIANT HALOGEN

FREE

Hyperfast Rectifier, 5 A FRED Pt®





DPAK (TO-252AA)

Single

DPAK (TO-252AA)

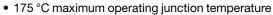
Package

Circuit configuration

PRIMARY CHARACTERISTICS					
I _{F(AV)}	5 A				
V _R	600 V				
V _F at I _F	1.2 V				
t _{rr} (typ.)	18 ns				
T ₁ may	175 °C				

FEATURES

 \bullet Hyperfast recovery time, reduced Q_{rr} and soft recovery



- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V_{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 150 °C	5			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	70	Α		
Peak repetitive forward current	I _{FM}	T _C = 150 °C, f = 20 kHz, d = 50 %	10			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	V _F	I _F = 5 A	-	1.54	1.85		
		I _F = 5 A, T _J = 150 °C	-	1.20	1.40		
Reverse leakage current	1	$V_R = V_R$ rated	-	-	5		
neverse leakage current	I _R	T _J = 150 °C, V _R = V _R rated	-	-	130	μA	
Junction capacitance	C _T	V _R = 600 V	=	3.5	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 A, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	18	-	
Bayaraa raaayan, tima	t _{rr}	$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	22	-	
Reverse recovery time		T _J = 25 °C	I _F = 5 A dI _F /dt = 200 A/μs V _R = 390 V	-	25	-	ns
		T _J = 125 °C		-	35	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.9	-	۸
		T _J = 125 °C		-	5.1	-	- A
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	51	-	- nC
		T _J = 125 °C		-	93	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case per leg	R _{thJC}		-	-	3	°C/W	
Approximate weight			0.3		g		
				0.01		OZ.	
Marking device		Case style DPAK (TO-252AA)		5EWH	06FNH		

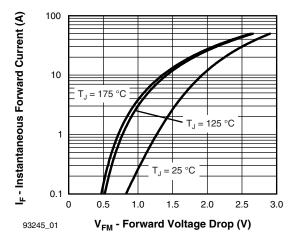


Fig. 1 - Typical Forward Voltage Drop Characteristics

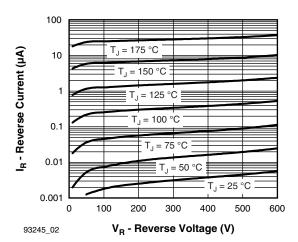


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

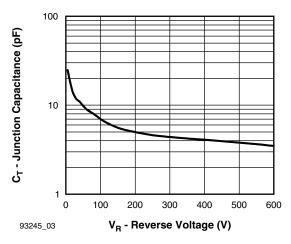


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

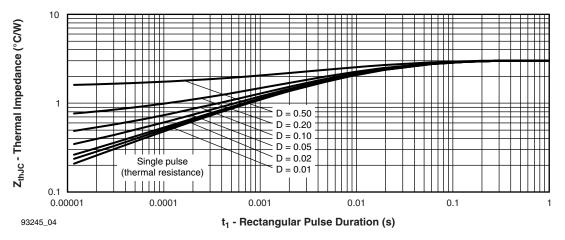


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

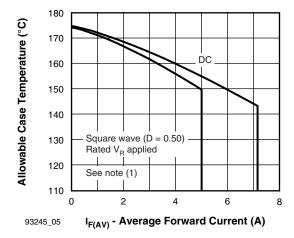


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

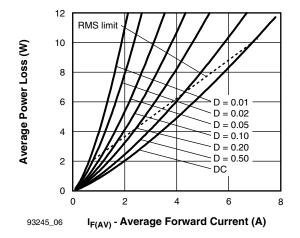


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

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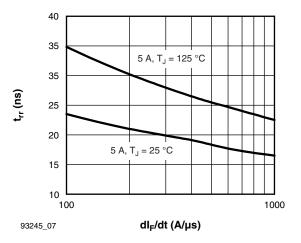


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

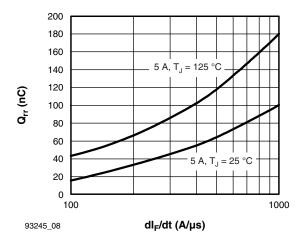
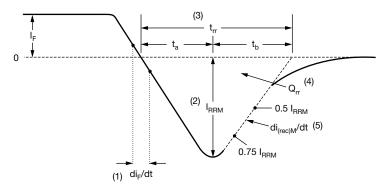


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_r$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

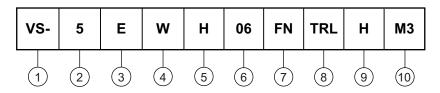
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (5 = 5 A)

Circuit configuration:

E = single diode

Package identifier:

W = D-PAK

5 - H = hyperfast recovery

6 - Voltage rating (06 = 600 V)

7 - FN = TO-252AA

8 - None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - H = AEC-Q101 qualified

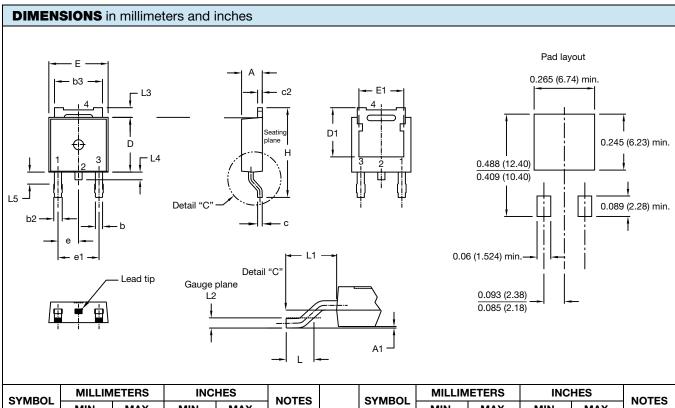
10 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-5EWH06FNHM3	75	3000	Antistatic plastic tube				
VS-5EWH06FNTRHM3	2000	2000	13" diameter reel				
VS-5EWH06FNTRLHM3	3000	3000	13" diameter reel				
VS-5EWH06FNTRRHM3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95519			
Part marking information	www.vishay.com/doc?95176			
Packaging information	www.vishay.com/doc?95518			
SPICE model	www.vishay.com/doc?95186			

DPAK (TO-252AA)



SYMBOL	MILLIN	MILLIMETERS		INCHES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIN	IETERS	INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29 BSC		0.090	0.090 BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	0.51 BSC		BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
	·	·		·	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (5) Outline conforms to JEDEC® outline TO-252AA



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